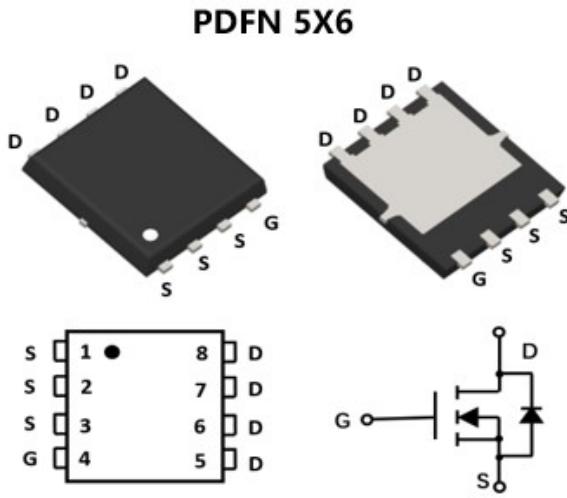




## N-Channel Enhancement Mode Field Effect Transistor



### Product Summary

- $V_{DS}$  40V
- $I_D$  90A
- $R_{DS(ON)}$  (at  $V_{GS} = 10V$ )  $< 4.5\text{mohm}$
- $R_{DS(ON)}$  (at  $V_{GS} = 4.5V$ )  $< 6.5\text{mohm}$
- 100% UIS Tested
- 100%  $\nabla V_{DS}$  Tested

### General Description

- Trench Power LV MOSFET technology
- Excellent package for heat dissipation
- High density cell design for low  $R_{DS(ON)}$

### Applications

- High current load applications
- Load switching
- Hard switched and high frequency circuits
- Uninterruptible power supply

#### ■ Absolute Maximum Ratings ( $T_A=25^\circ\text{C}$ unless otherwise noted)

Parameter		Symbol	Limit	Unit
Drain-source Voltage		$V_{DS}$	40	V
Gate-source Voltage		$V_{GS}$	$\pm 20$	V
Drain Current	$T_c=25^\circ\text{C}$	$I_D$	90	A
	$T_c=100^\circ\text{C}$		63	
Pulsed Drain Current <sup>A</sup>		$I_{DM}$	340	A
Total Power Dissipation	$T_c=25^\circ\text{C}$	$P_D$	55	W
	$T_c=100^\circ\text{C}$		27.5	
Single Pulse Avalanche Energy <sup>B</sup>		$E_{AS}$	220	mJ
Thermal Resistance Junction-to-Case <sup>C</sup>		$R_{\theta JC}$	2.73	$^\circ\text{C}/\text{W}$
Junction and Storage Temperature Range		$T_J, T_{STG}$	-55~+175	$^\circ\text{C}$

#### ■ Ordering Information (Example)

PREFERRED P/N	PACKING CODE	Marking	MINIMUM PACKAGE(pcs)	INNER BOX QUANTITY(pcs)	OUTER CARTON QUANTITY(pcs)	DELIVERY MODE
YJG90N04A	F1	YJG90N04A	5000	10000	100000	13" reel

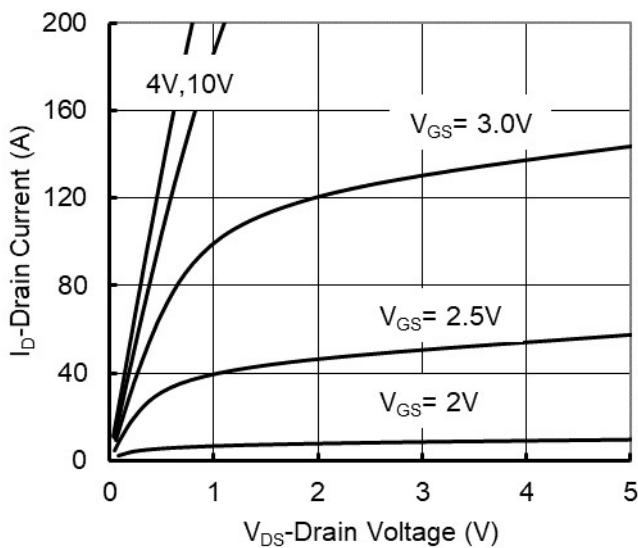
**■ Electrical Characteristics (T<sub>J</sub>=25°C unless otherwise noted)**

Parameter	Symbol	Conditions	Min	Typ	Max	Units
<b>Static Parameter</b>						
Drain-Source Breakdown Voltage	BV <sub>DSS</sub>	V <sub>GS</sub> = 0V, I <sub>D</sub> =250μA	40			V
Zero Gate Voltage Drain Current	I <sub>DSS</sub>	V <sub>DS</sub> =40V, V <sub>GS</sub> =0V			1	μA
Gate-Body Leakage Current	I <sub>GSS</sub>	V <sub>GS</sub> = ±20V, V <sub>DS</sub> =0V			±100	nA
Gate Threshold Voltage	V <sub>GS(th)</sub>	V <sub>DS</sub> = V <sub>GS</sub> , I <sub>D</sub> =250μA	0.7	1.2	2.0	V
Static Drain-Source On-Resistance	R <sub>DS(ON)</sub>	V <sub>GS</sub> = 10V, I <sub>D</sub> =20A		3.5	4.5	mΩ
		V <sub>GS</sub> = 4.5V, I <sub>D</sub> =20A		4.4	6.5	
Diode Forward Voltage	V <sub>SD</sub>	I <sub>S</sub> =20A, V <sub>GS</sub> =0V		0.85	1.2	V
Maximum Body-Diode Continuous Current	I <sub>S</sub>				90	A
<b>Dynamic Parameters</b>						
Input Capacitance	C <sub>iss</sub>	V <sub>DS</sub> =20V, V <sub>GS</sub> =0V, f=1MHZ		3440		pF
Output Capacitance	C <sub>oss</sub>			413		
Reverse Transfer Capacitance	C <sub>rss</sub>			314		
<b>Switching Parameters</b>						
Total Gate Charge	Q <sub>g</sub>	V <sub>GS</sub> =10V, V <sub>DS</sub> =20, I <sub>D</sub> =20A		10.9		nC
Gate-Source Charge	Q <sub>gs</sub>			19.7		
Gate-Drain Charge	Q <sub>gd</sub>			89		
Reverse Recovery Charge	Q <sub>rr</sub>	I <sub>F</sub> =20A, di/dt=100A/us		7.3		ns
Reverse Recovery Time	t <sub>rr</sub>			24		
Turn-on Delay Time	t <sub>D(on)</sub>			9		
Turn-on Rise Time	t <sub>r</sub>	V <sub>GS</sub> =10V, V <sub>DD</sub> =20V, I <sub>D</sub> =2A, R <sub>L</sub> =1Ω R <sub>GEN</sub> =3Ω		20		ns
Turn-off Delay Time	t <sub>D(off)</sub>			69		
Turn-off fall Time	t <sub>f</sub>			41		

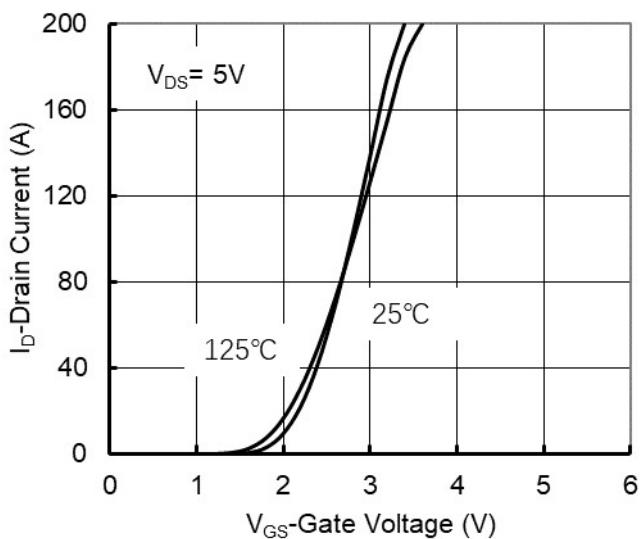
A. Pulse Test: Pulse Width≤300us, Duty cycle ≤2%.

B. R<sub>θJA</sub> is the sum of the junction-to-case and case-to-ambient thermal resistance, where the case thermal reference is defined as the solder mounting surface of the drain pins. R<sub>θJC</sub> is guaranteed by design, while R<sub>θJA</sub> is determined by the board design. The maximum rating presented here is based on mounting on a 1 in 2 pad of 2oz copper.

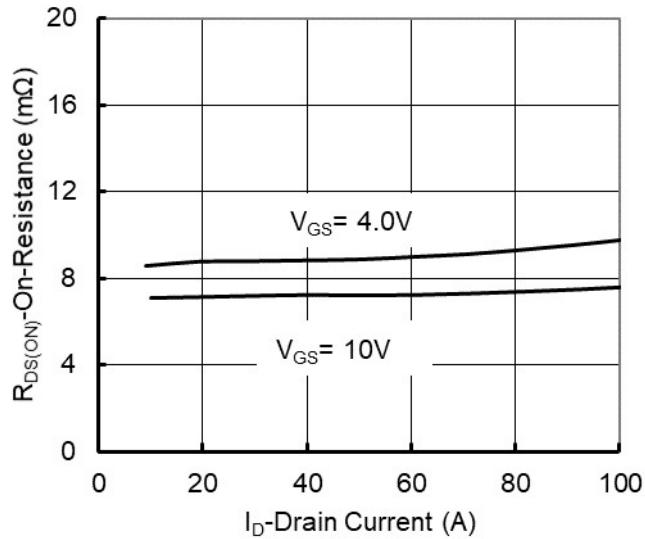
## ■ Typical Performance Characteristics



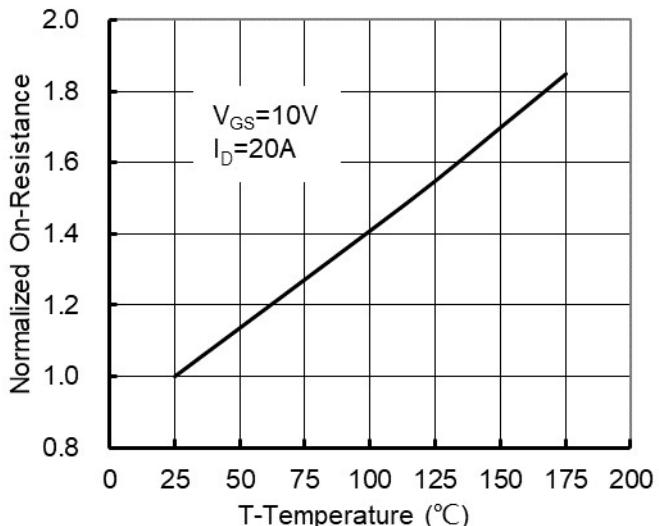
**Figure 1. Output Characteristics**



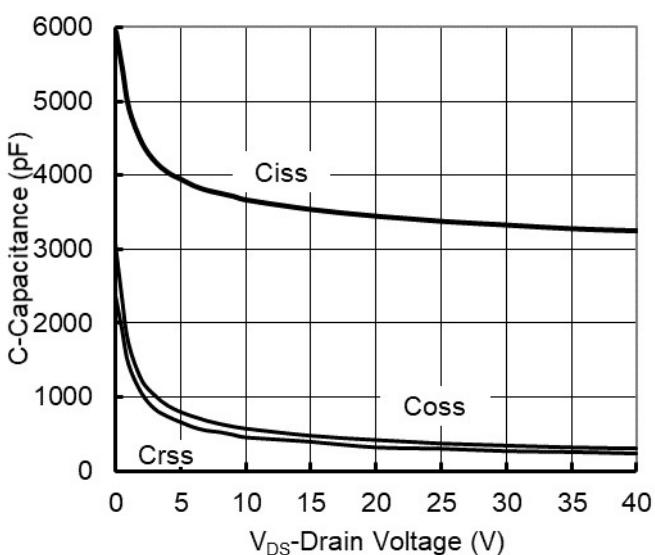
**Figure 2. Transfer Characteristics**



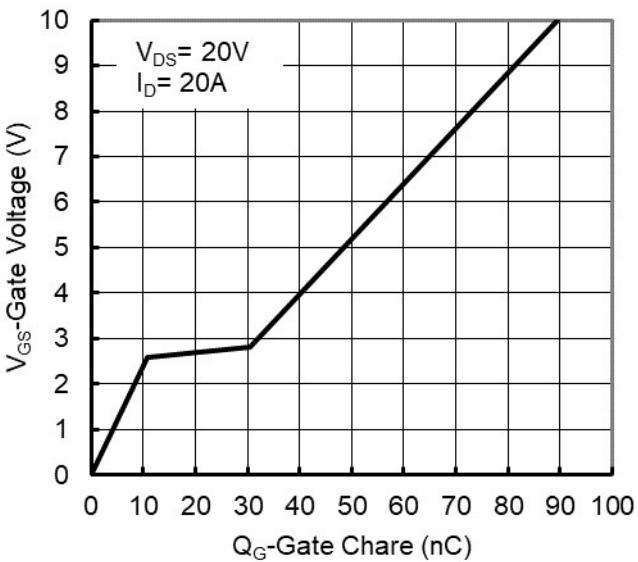
**Figure 3. On-Resistance vs. Drain Current and Gate Voltage**



**Figure 4. On-Resistance vs. Junction Temperature**



**Figure 5. Capacitance Characteristics**



**Figure 6. Gate Charge**

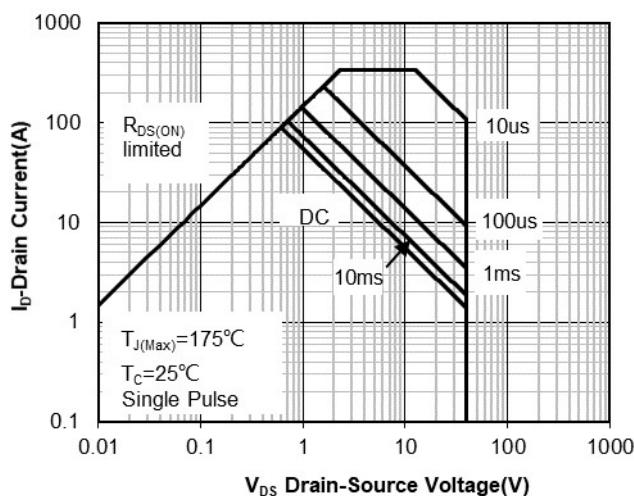


Figure 7. Safe Operation Area

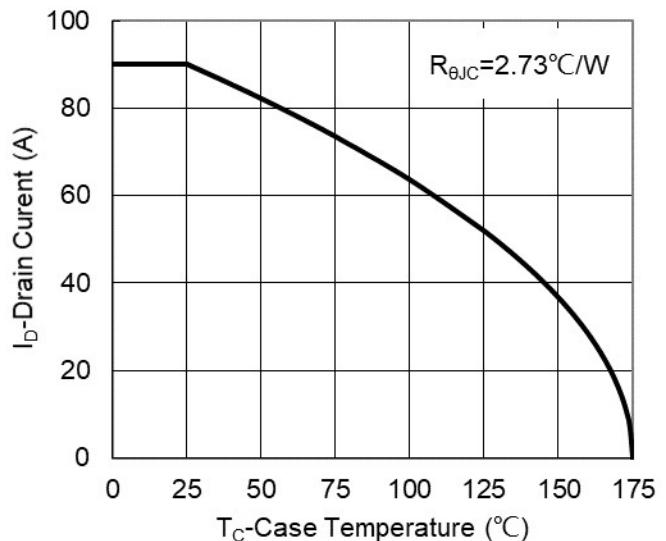


Figure 8. Maximum Continuous Drain Current vs Case Temperature

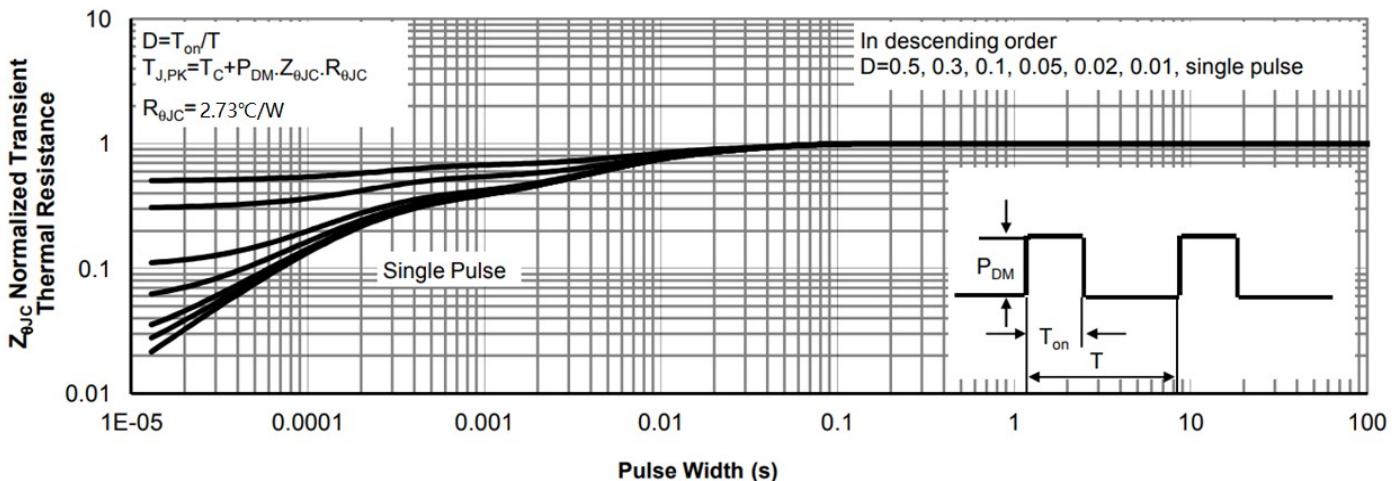
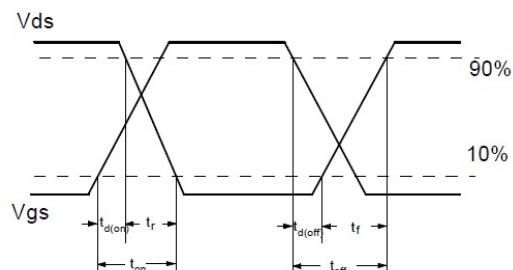
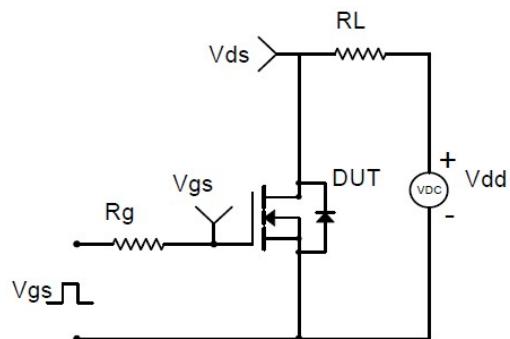
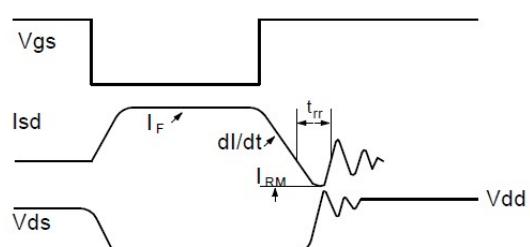
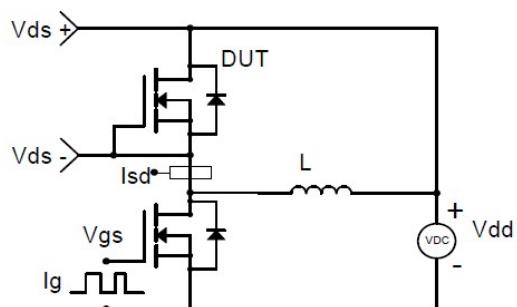


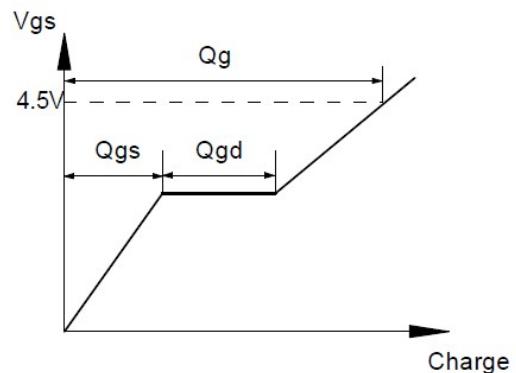
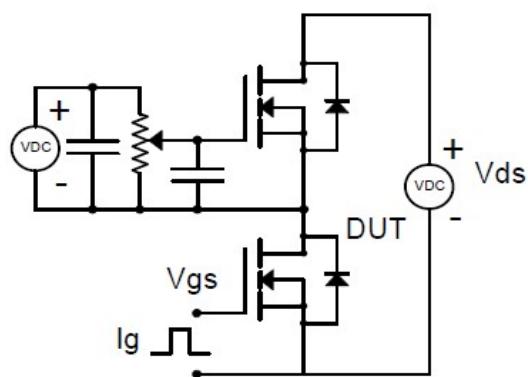
Figure 9. Normalized Maximum Transient Thermal Impedance



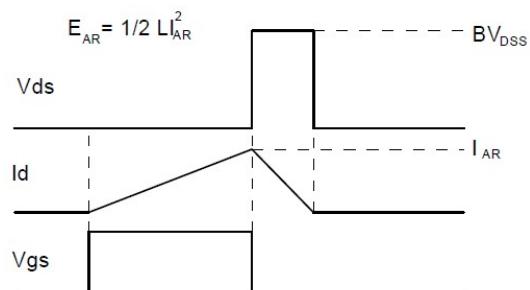
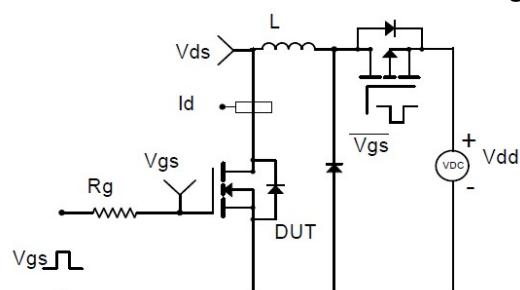
Resistive Switching Test Circuit &amp; Waveforms



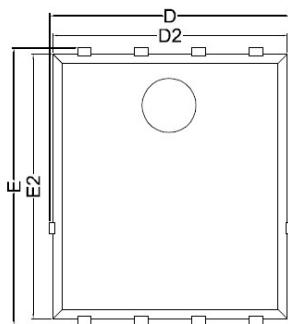
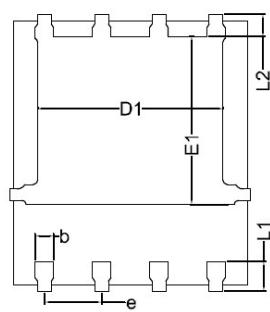
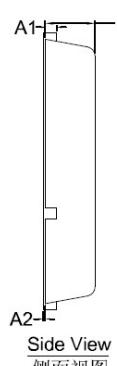
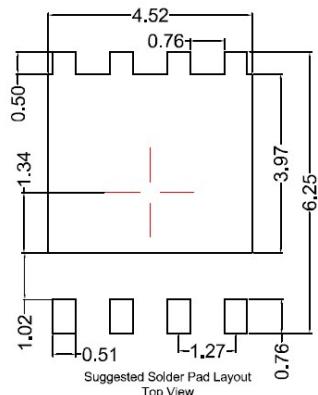
Diode Recovery Test Circuit &amp; Waveforms



Gate Charge Test Circuit &amp; Waveform



Unclamped Inductive Switching (UIS) Test Circuit &amp; Waveforms

**■ PDFN5X6 Package information**Top View  
正面视图Bottom View  
背面视图Side View  
侧面视图Suggested Solder Pad Layout  
Top View

SYMBOL	MILLIMETER		
	MIN	NOM	MAX
D	5.15	5.35	5.55
E	5.95	6.15	6.35
A	1.00	1.10	1.20
A1		0.254 BSC	
A2			0.10
D1	3.92	4.12	4.32
E1	3.52	3.72	3.92
D2	5.00	5.20	5.40
E2	5.66	5.86	6.06
L1	0.56	0.66	0.76
L2		0.50 BSC	
b	0.31	0.41	0.51
e		1.27 BSC	

## Note:

1. Controlling dimension: in millimeters.
2. General tolerance:  $\pm 0.10$ mm.
3. The pad layout is for reference purposes only.



## Disclaimer

The information presented in this document is for reference only. Yangzhou Yangjie Electronic Technology Co., Ltd. reserves the right to make changes without notice for the specification of the products displayed herein to improve reliability, function or design or otherwise.

The product listed herein is designed to be used with ordinary electronic equipment or devices, and not designed to be used with equipment or devices which require high level of reliability and the malfunction of which would directly endanger human life (such as medical instruments, transportation equipment, aerospace machinery, nuclear-reactor controllers, fuel controllers and other safety devices), Yangjie or anyone on its behalf, assumes no responsibility or liability for any damages resulting from such improper use of sale.

This publication supersedes & replaces all information previously supplied. For additional information, please visit our website <http://www.21yangjie.com>, or consult your nearest Yangjie's sales office for further assistance.